



v01.0214

HMC1063LP3E

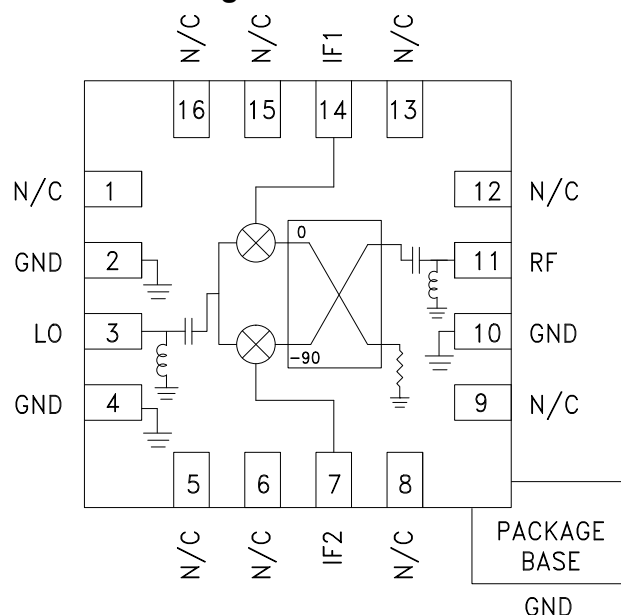
GaAs MMIC I/Q MIXER 24 - 28 GHz

Typical Applications

The HMC1063LP3E is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications
- Sensors

Functional Diagram



Features

- Low LO Power: 10 dBm
- Wide IF Bandwidth: DC - 3 GHz
- Image Rejection: 21 dBc
- LO / RF Isolation: 40 dB
- High Input IP3: 17 dBm
- 16 Lead 3x3 mm SMT Package: 9 mm²

General Description

The HMC1063LP3E is a compact I/Q MMIC mixer in a leadless "Pb free" SMT package, which can be used as either an Image Reject Mixer or a Single Sideband Upconverter. The mixer utilizes two standard Hittite double balanced mixer cells and a 90 degree hybrid fabricated in a GaAs Schottky diode process. A low frequency quadrature hybrid was used to produce a 1000 MHz LSB IF output. This product is a much smaller alternative to hybrid style Image Reject Mixers and Single Sideband Upconverter assemblies. The HMC1063LP3E eliminates the need for wire bonding and allows the use of surface mount manufacturing techniques.

Electrical Specifications ^{[1][2]}, $T_A = +25^\circ\text{C}$, IF = 1000 MHz, LSB, LO = +10 dBm

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range, RF		24 - 27			27- 28		GHz
Frequency Range, LO		21 - 30			24 - 31		GHz
Frequency Range, IF		DC - 3			DC - 3		GHz
Conversion Gain	-11.5	-9.5		-11.5	-9.5		dB
Image Rejection	15	21		13	21		dBc
LO to RF Isolation	30	42		28	36		dB
LO to IF Isolation		40			40		dB
IP3 (Input)		18			16		dBm
Amplitude Balance ^[2]		1			1		dB
Phase Balance ^[2]		-2			+2		Deg

[1] Unless otherwise noted all measurements performed as downconverter.

[2] Data taken without external 90° hybrid.

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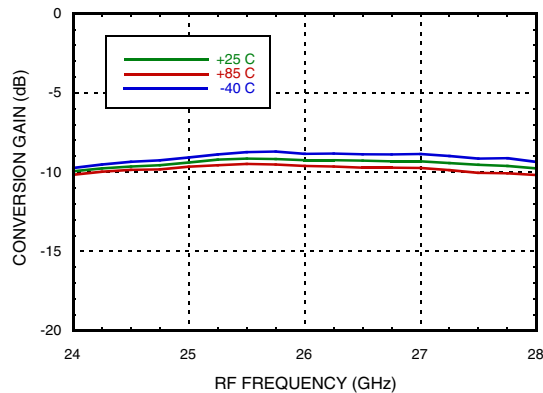
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D



**GaAs MMIC I/Q MIXER
24 - 28 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

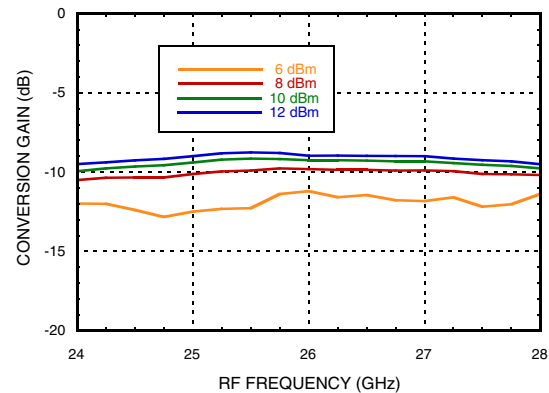


Image Rejection, LSB vs. Temperature

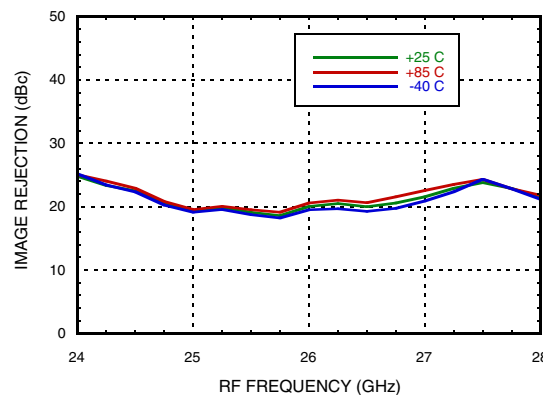
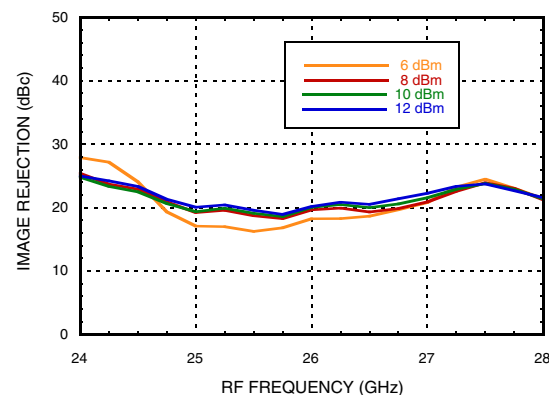
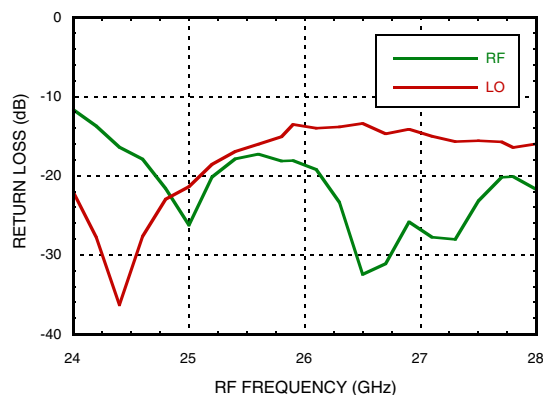


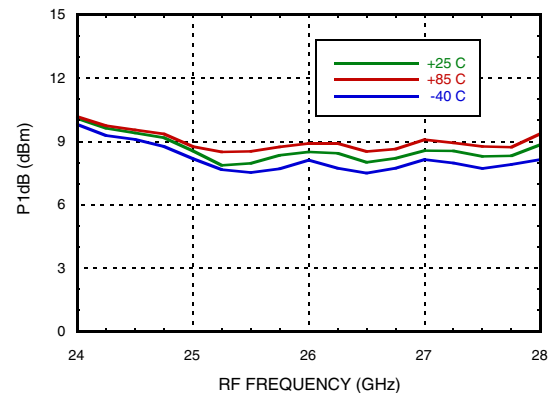
Image Rejection, LSB vs. LO Drive



Return Loss



Input P1dB, LSB vs. Temperature



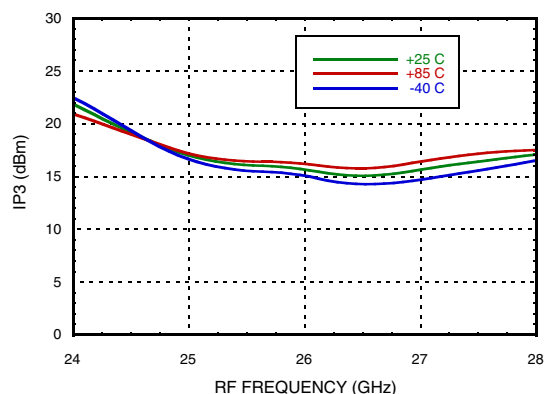
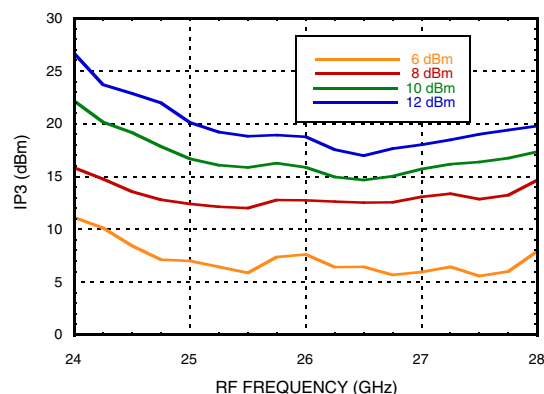
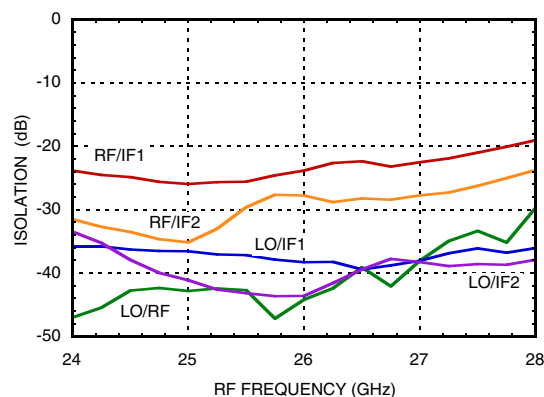
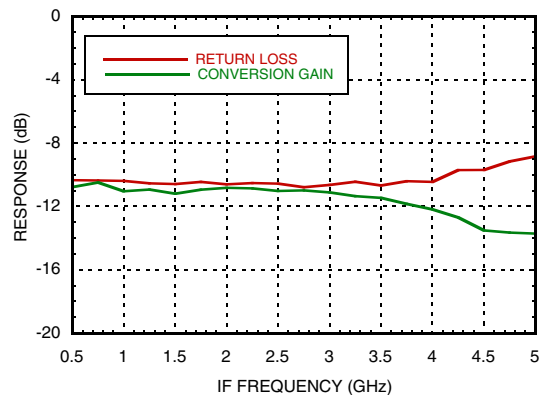
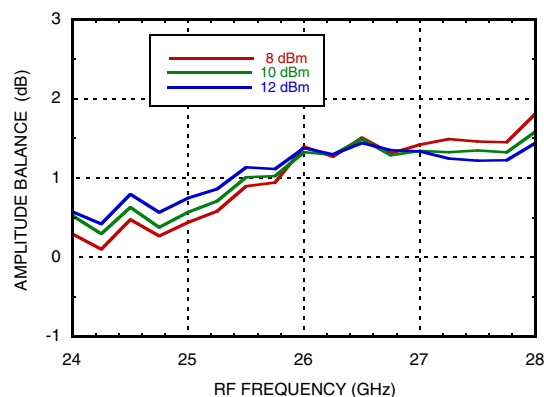
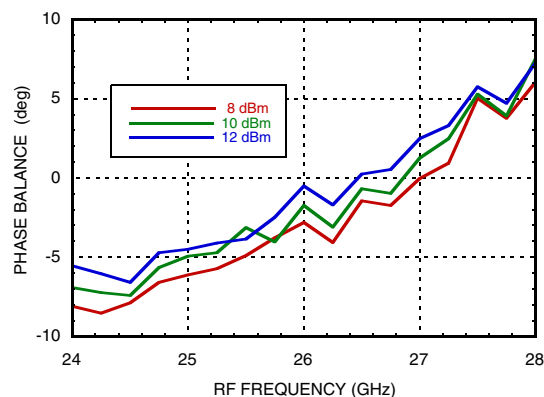
[1] Data taken without external IF 90° hybrid

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Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

Input IP3, LSB vs. Temperature

Input IP3, LSB vs. LO Drive

Isolations

IF Bandwidth*

Amplitude Balance, LSB vs. LO Drive

Phase Balance, LSB vs. LO Drive


* Conversion gain data taken with external IF hybrid.

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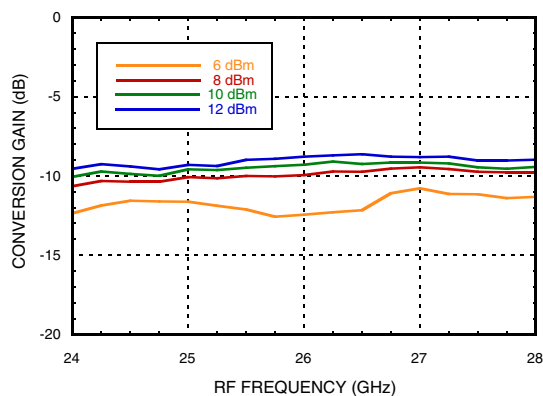
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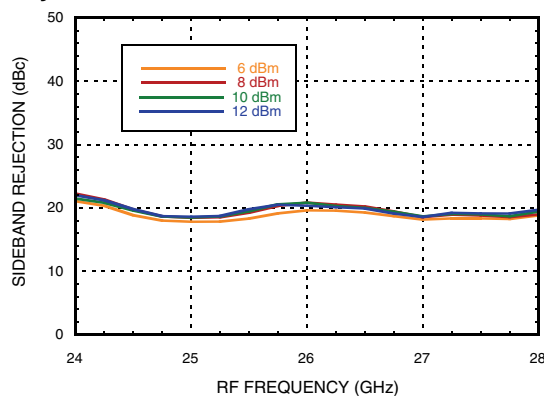
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Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

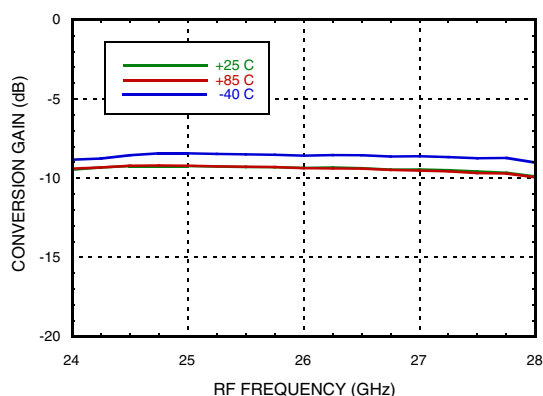
Upconverter Performance, Conversion Gain, LSB vs. LO Drive



Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

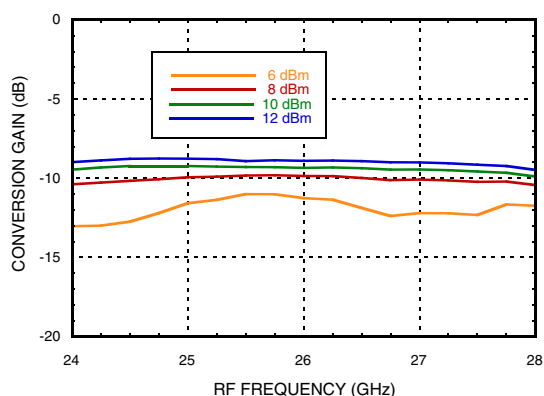


Image Rejection, USB vs. Temperature

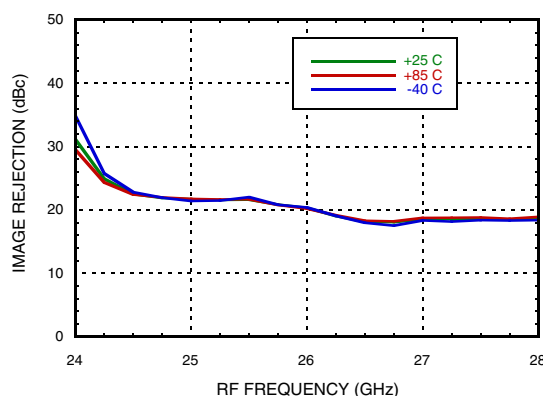
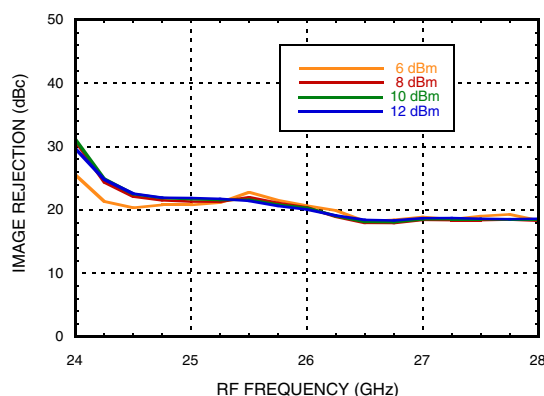
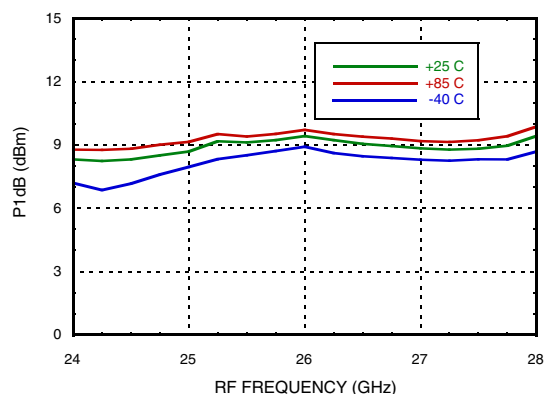
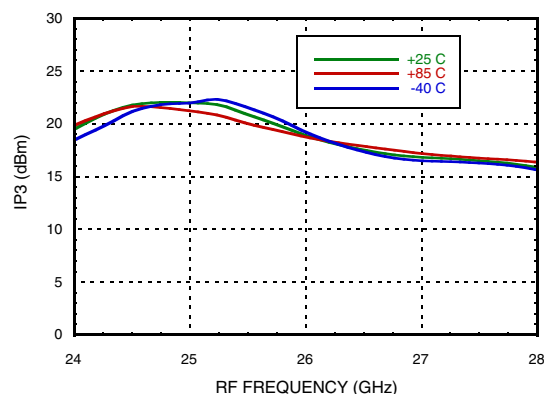
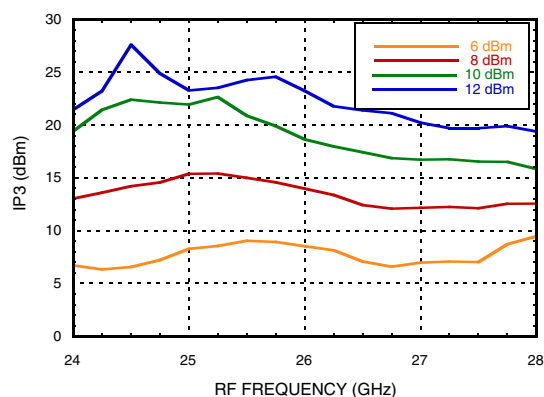
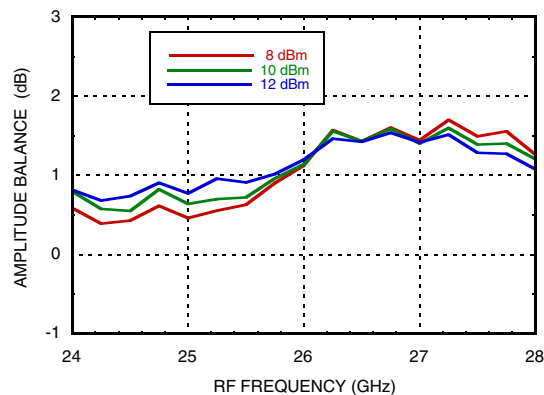
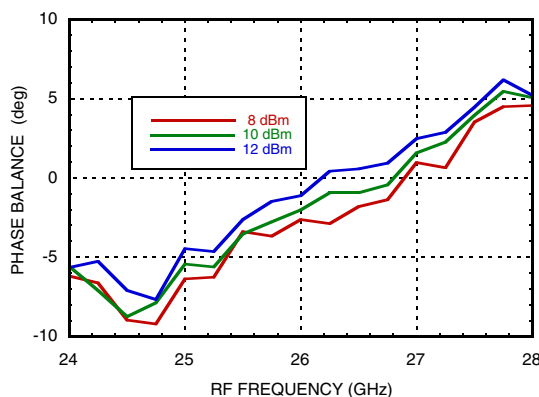


Image Rejection, USB vs. LO Drive




**GaAs MMIC I/Q MIXER
24 - 28 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

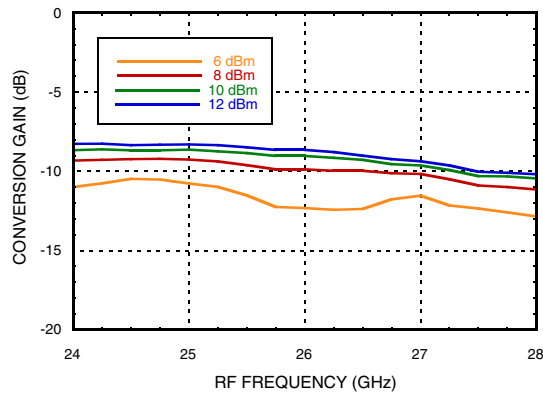
Input P1dB, USB vs. Temperature

Input IP3, USB vs. Temperature

Input IP3, USB vs. LO Drive

Amplitude Balance, USB vs. LO Drive

Phase Balance, USB vs. LO Drive




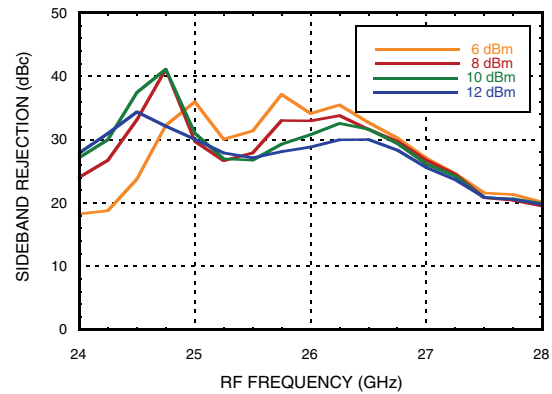
**GaAs MMIC I/Q MIXER
24 - 28 GHz**

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 1000 MHz

Upconverter Performance, Conversion Gain, USB vs. LO Drive

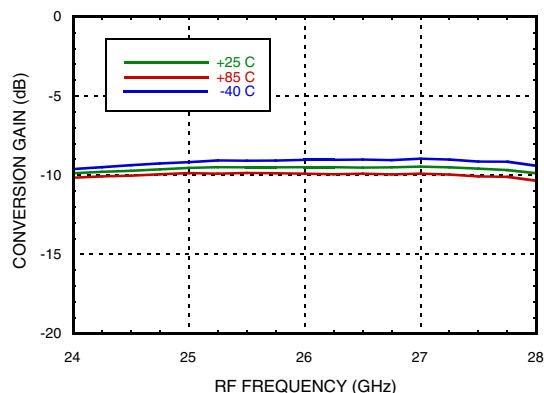
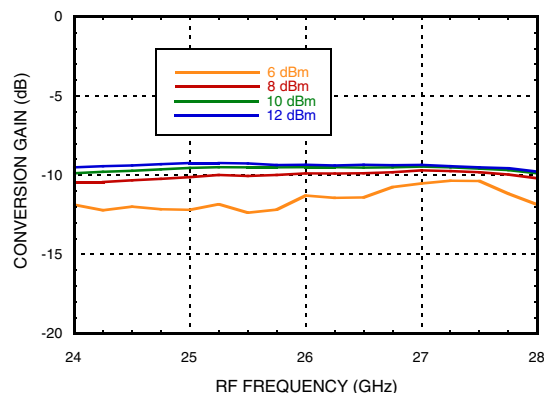
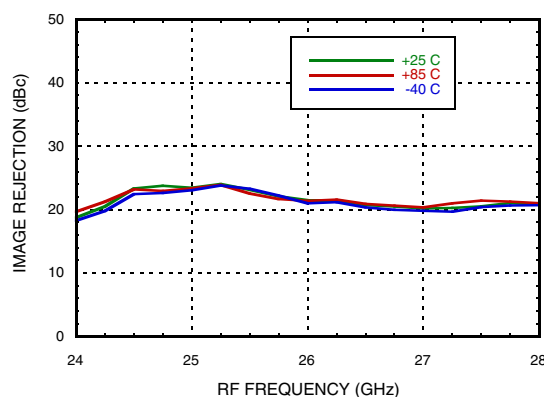
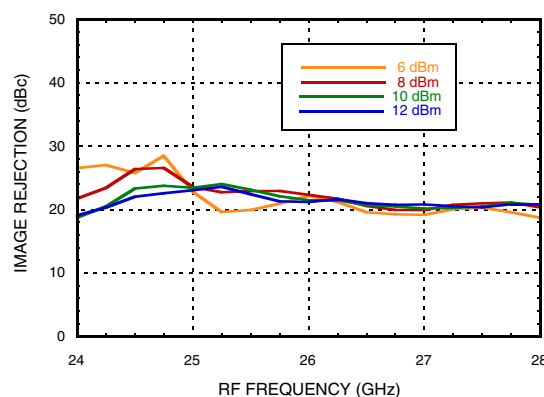
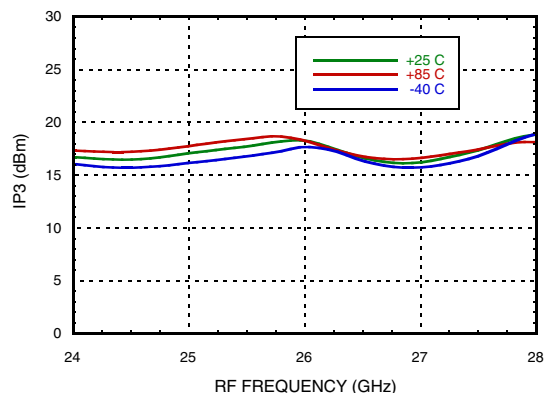
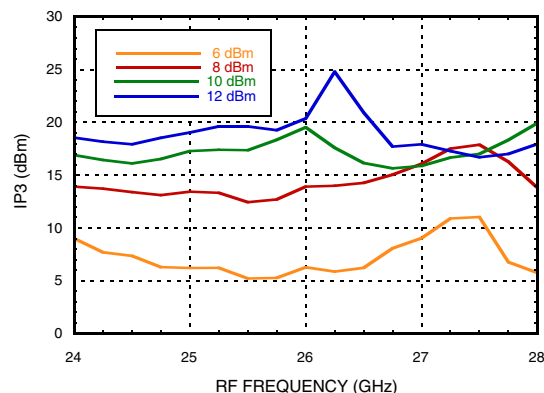


Upconverter Performance, Sideband Rejection, USB vs. LO Drive,




**GaAs MMIC I/Q MIXER
24 - 28 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

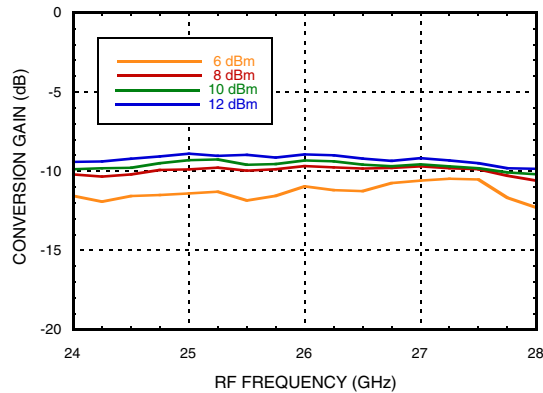
Conversion Gain, LSB vs. Temperature

Conversion Gain, LSB vs. LO Drive

Image Rejection, LSB vs. Temperature

Image Rejection, LSB vs. LO Drive

Input IP3, LSB vs. Temperature

Input IP3, LSB vs. LO Drive




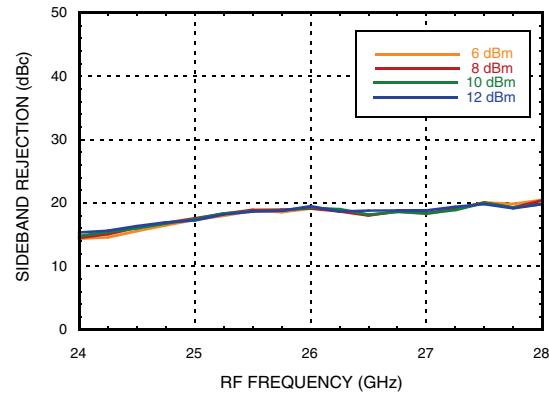
**GaAs MMIC I/Q MIXER
24 - 28 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

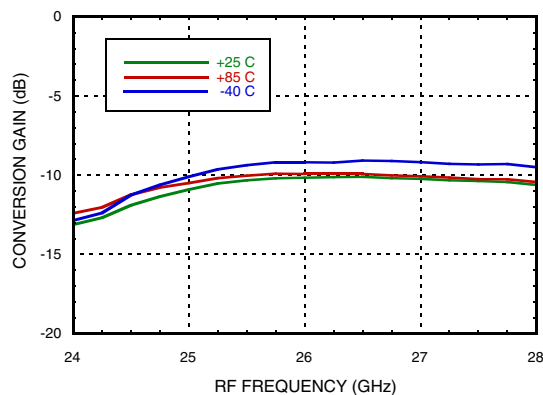
Upconverter Performance, Conversion Gain, LSB vs. LO Drive



Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

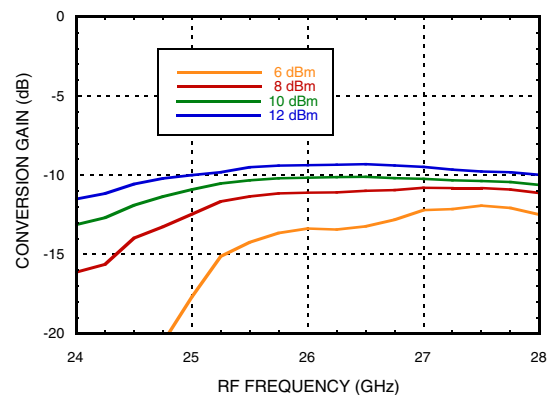


Image Rejection, USB vs. Temperature

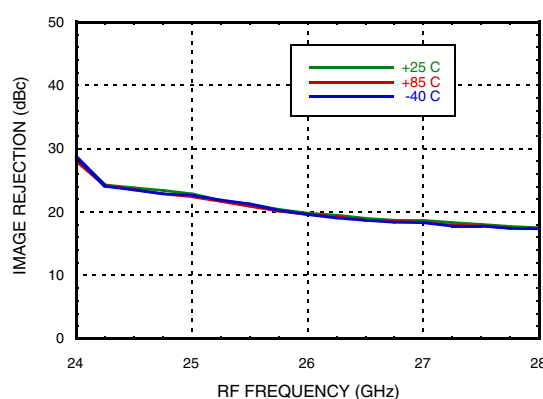
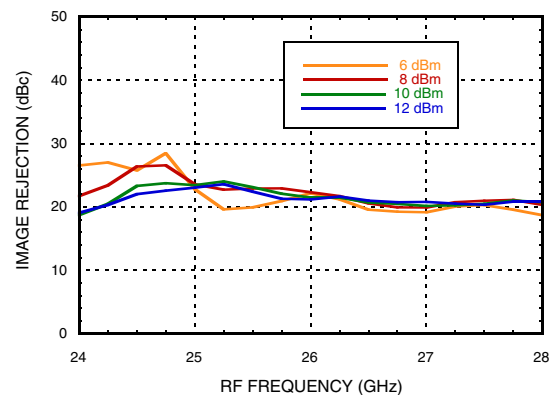
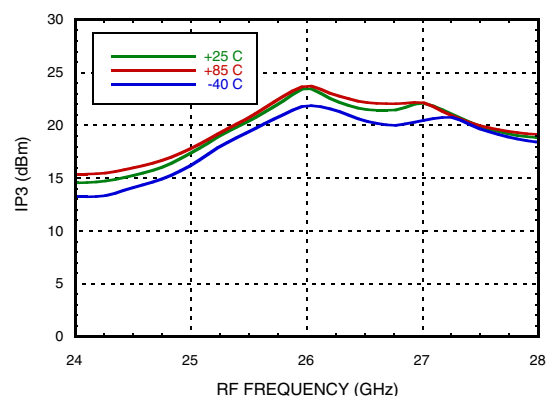
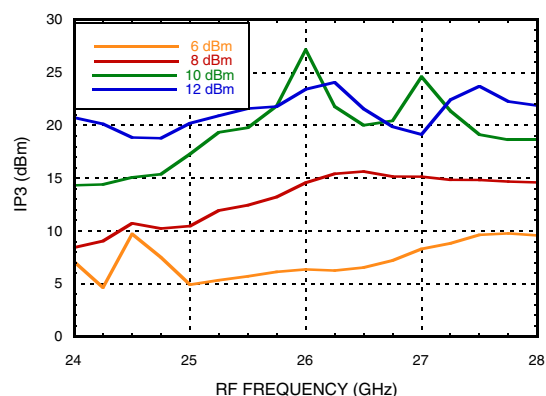
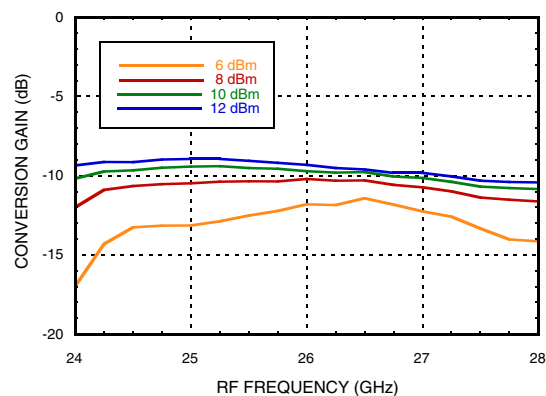
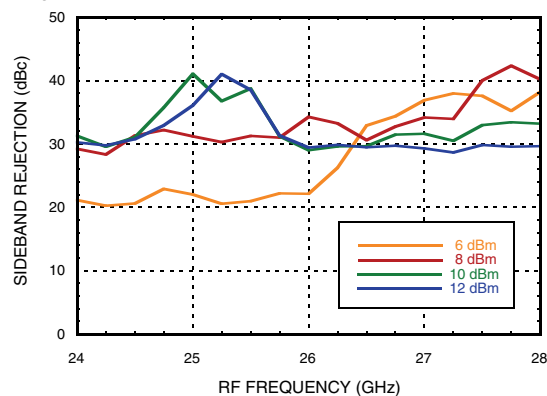


Image Rejection, USB vs. LO Drive




**GaAs MMIC I/Q MIXER
24 - 28 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

Input IP3, USB vs. Temperature

Input IP3, USB vs. LO Drive

Upconverter Performance, Conversion Gain, USB vs. LO Drive

Upconverter Performance, Sideband Rejection, USB vs. LO Drive,




Harmonics of LO

LO Freq. (GHz)	nLO Spur at RF Port		
	1	2	3
23	36.6	43.3	x
24	33.8	46.4	x
25	32.1	49.4	x
26	29.6	x	x
27	31.8	x	x
28	32.8	x	x

LO = + 10 dBm
Values in dBc below LO level measured at RF Port.

MxN Spurious Outputs

mRF	nLO				
	0	1	2	3	4
0	XX	1	28	x	x
1	8	0	34	60	x
2	95	53	51	58	87
3	x	97	97	97	97
4	x	x	x	97	97

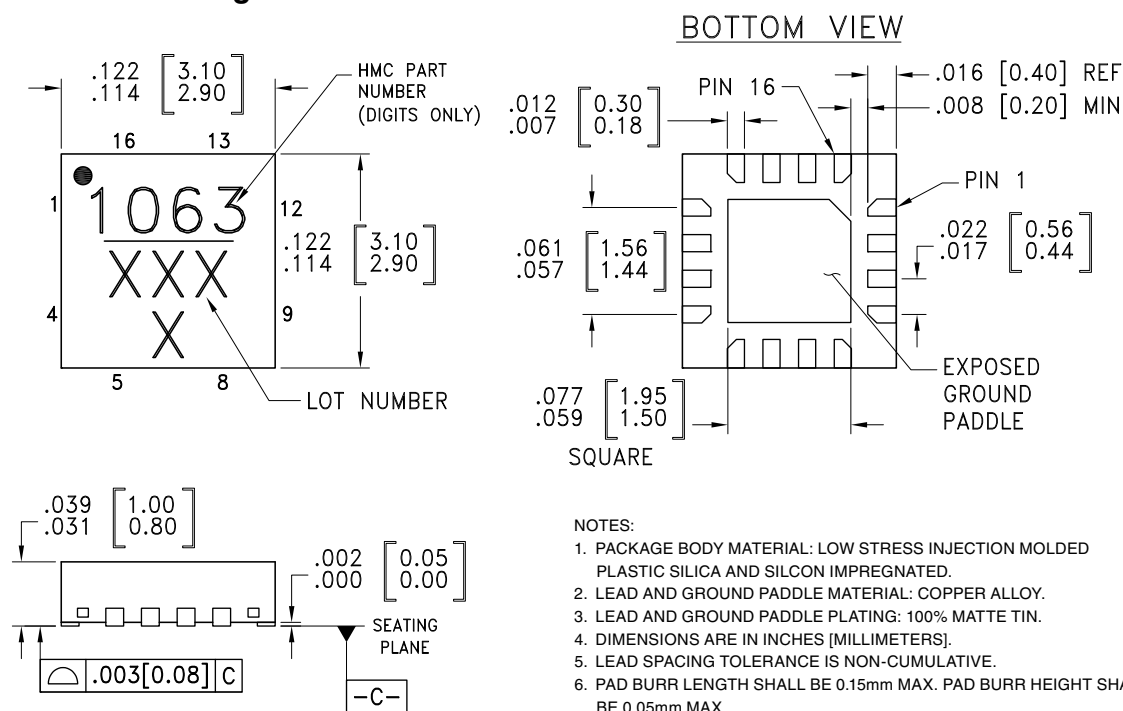
RF = 22 GHz @ -10 dBm
LO = 23 GHz @ +10 dBm
Data taken without IF hybrid
All values in dBc below IF power level


**GaAs MMIC I/Q MIXER
24 - 28 GHz**
Absolute Maximum Ratings

IF Input (At LO = 10 dBm and RF = -10 dBm)	+11.5 dBm
RF Input (At 10 dBm LO Power)	+13 dBm
LO Input (At -10 dBm RF Power)	+14.5 dBm
Channel Temperature	175 °C
Continuous P _{diss} (T = 85°C) (derate 6 mW/°C above 85°C)	550 mW
Thermal Resistance (channel to ground paddle)	164 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**


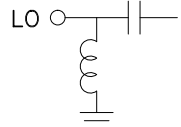
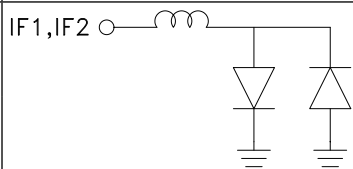
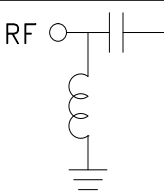
Outline Drawing

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating ^[2]	Package Marking ^[1]
HMC1063LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1	H1063 XXXX

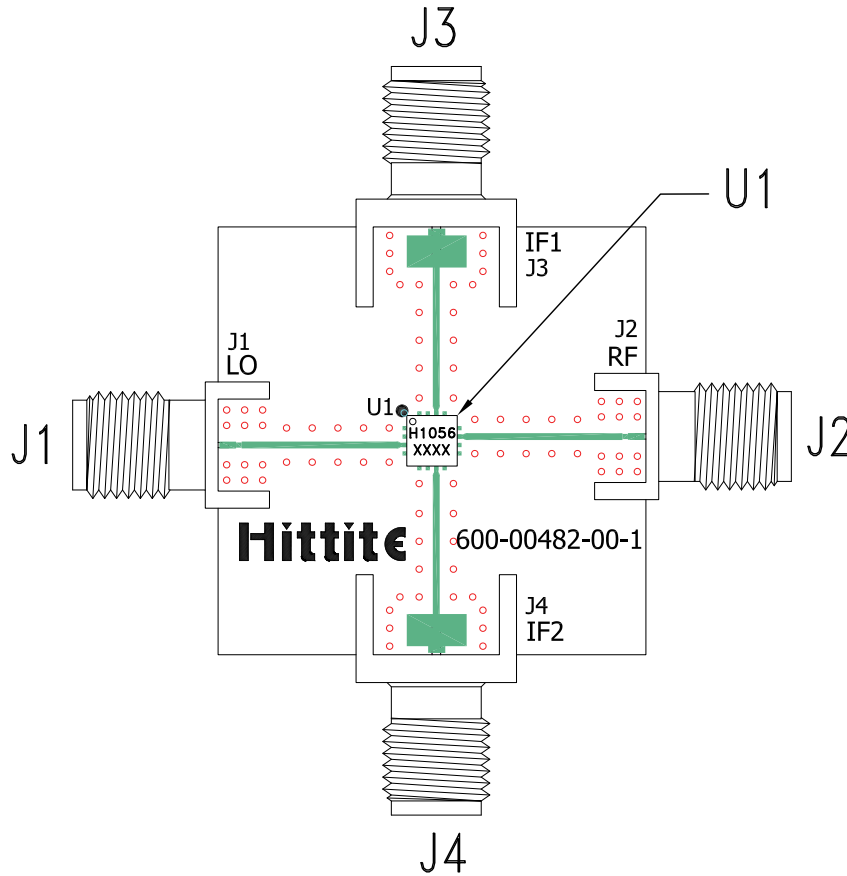
[1] 4-Digit lot number XXXX

[2] Max peak reflow temperature of 260 °C

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 5, 6, 8, 9, 12, 13, 15, 16	N/C	These pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
2, 4, 10	GND	These pins and exposed ground paddle must be connected to RF/DC ground	
3	LO	This pin is DC coupled and matched to 50 Ohms	
7	IF2	Differential IF input pins. For applications not requiring operation to DC, an off chip DC blocking capacitor should be used. For operation to DC this pin must not source/sink more than 3 mA of current or part non function and and possible part failure will result.	
14	IF1		
11	RFOUT	This pin is DC coupled and matched to 50 Ohms.	

Evaluation PCB



List of Materials for Evaluation PCB EVAL01-HMC1063LP3 [1]

Item	Description
J1, J2	PCB mount K Connector SRI
J3, J4	PCB mount SMA Connector Johnson
U1	HMC1063LP3E Downconverter
PCB [2]	600-00482-00-1 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR, FR4 or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

**Notes:**

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- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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